



General Description

The AOZ8822 is an ultra-low capacitance two-line transient voltage suppressor diode designed to protect very high-speed data lines and voltage sensitive electronics from high transient conditions and ESD.

This device incorporates two TVS diodes in an ultra-small DFN 1.0 x 0.6 package. During transient conditions, the ultra-low capacitance TVS diodes directs the transient to ground. The AOZ8822 may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (\pm 15 kV air, \pm 15 kV contact discharge).

The AOZ8822 comes in an RoHS compliant 3-lead DFN package and is rated over a -40 °C to +85 °C ambient temperature range.

The ultra-small 1.0 mm x 0.6 mm x 0.5 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

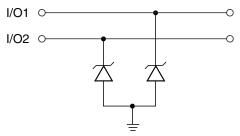
- ESD protection for high-speed data lines:
 - Exceeds: IEC 61000-4-2 (ESD) ± 15 kV (air),± 15 kV (contact)
 - Human Body Model (HBM) ± 15 kV
- Ultra-low capacitance: 0.55 pF
- Low clamping voltage
- Low operating voltage: 5 V
- Green product

Applications

- Portable handheld devices
- Keypads, data lines, buttons
- Notebook computers
- Digital Cameras
- Portable GPS
- MP3 players

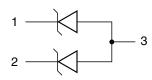


Typical Application



Unidirection Protection of Two Line

Pin Configuration





Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental		
AOZ8822DI-05	-40 °C to +85 °C	DFN 1.0 x 0.6	Green Product		



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

 $Please\ visit\ www.aosmd.com/media/AOSGreenPolicy.pdf\ for\ additional\ information.$

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
VP – VN	5 V
Peak Pulse Current (I _{PP}), t _P = 8/20μs	2 A
Storage Temperature (T _S)	-65 °C to +150 °C
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	± 15 kV
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	± 15 kV
ESD Rating per Human Body Model ⁽²⁾	± 15 kV

Notes:

- 1. IEC 61000-4-2 discharge with C $_{\rm Discharge}$ = 150 pF, R $_{\rm Discharge}$ = 330 $\Omega.$
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100pF, $R_{Discharge}$ = 1.5 k Ω .

Maximum Operating Ratings

Parameter	Rating
Junction Temperature (T _J)	-40 °C to +125 °C



Electrical Characteristics

 T_A = 25°C unless otherwise specified. Specifications in **BOLD** indicate a temperature range of -40 °C to +85 °C.

Symbol	Parameter	Diagram
I _{PP}	Maximum Reverse Peak Pulse Current	ı
V _{CL}	Clamping Voltage @ I _{PP}	l
V _{RWM}	Working Peak Reverse Voltage	
I _R	Maximum Reverse Leakage Current]
V _{BR}	Breakdown Voltage]]
I _T	Test Current	VCLVBR VRWM VF
I _F	Forward Current	IR VF
V _F	Forward Voltage	
P _{PK}	Peak Power Dissipation	Ipp
CJ	Capacitance @ V _R = 0 and f = 1MHz	I

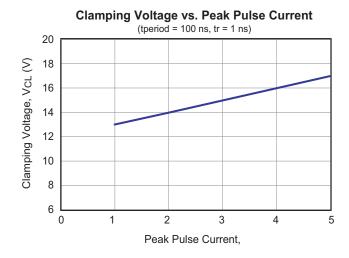
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage ⁽³⁾	I/O pin to ground			5.0	V
V_{BR}	Reverse Breakdown Voltage ⁽⁴⁾	I _T = 1 mA, I/O pin to ground	6.0		10.0	V
I _R	Reverse Leakage Current	V _{RWM} = 5 V, between I/O pin to ground			0.1	μΑ
		I_{PP} = 1 A, t_P = 100 ns, I/O pin to ground			13	V
		I_{PP} = 2 A, t_P = 100 ns, I/O pin to ground			14	V
		I_{PP} = 5 A, t_P = 100 ns, I/O pin to ground			17	V
V _{CL}	Channel Clamp Voltage	I _{PP} = 1 A, IEC61000-4-5, 8/20 μs, I/O pin to ground			14.5	V
		I _{PP} = 2 A, IEC61000-4-5, 8/20 μs, I/O pin to ground			19	V
CJ	Junction Capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, I/O \text{ pin to ground}$		0.55	0.75	pF

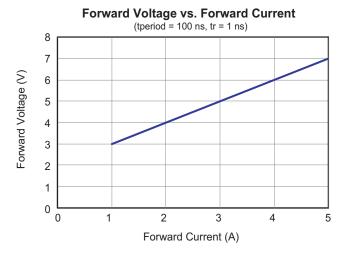
Notes:

- $3. \ The \ working \ peak \ reverse \ voltage \ (V_{RWM}) \ should \ be \ equal \ to \ or \ greater \ than \ the \ DC \ or \ continuous \ peak \ operating \ voltage \ level.$
- 4. V_{BR} is measured at the pulse test current I_{T} .

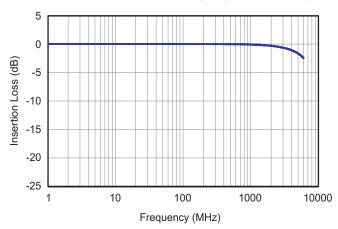


Typical Performance Characteristics



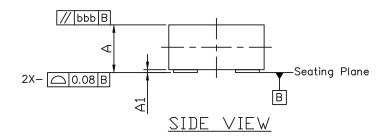


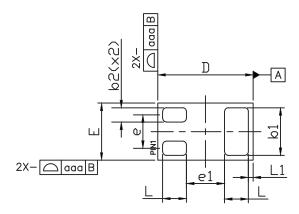






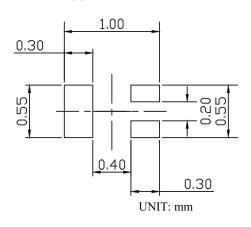
Package Dimensions, DFN1.0x0.6





BOTTOM VIEW

RECOMMENDED LAND PATTERN



SYMBOLS	DIMENS	IONS IN MIL	LIMETERS	DIMENSIONS IN INCHES			
STRIBULS	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0.47	0.52	0.55	0.019	0.020	0.022	
A1	0.00	0.03	0.05	0.000	0.001	0.002	
b1	0.45	0.50	0.55	0.018	0.020	0.022	
b2	0.10	0.15	0.20	0.004	0.006	0.008	
D	0.95	1.00	1.05	0.037	0.039	0.041	
E	0.55	0.60	0.65	0.022	0.024	0.026	
е		0.35			0.014		
e1		0.40			0.016		
L	0.20	0.25	0.30	0.008	0.010	0.012	
L1		0.05			0.002		
aaa		0.15			0.006		
bbb		0.05		0.002			

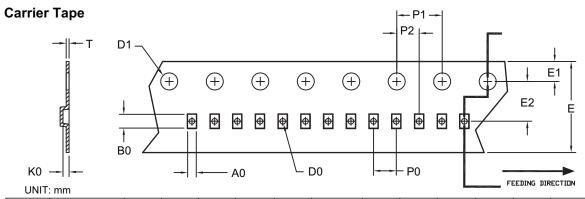
NOTE

- 1. ALL DIMENSION ARE IN MILLIMETERS.ANGLES ARE IN DEGREES.
- 2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.

Rev. 5.0 November 2018 **www.aosmd.com** Page 5 of 7

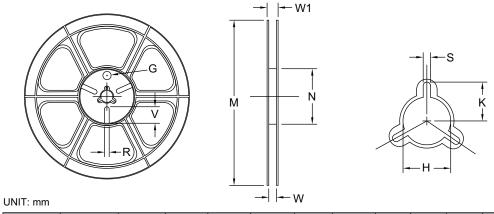


Tape and Reel Dimensions, DFN1.0x0.6



Option	Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	2.00 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.05

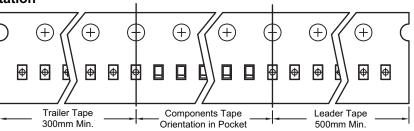




Tape Size	Reel Size	М	N	w	W1	Н	K	S	G	R	V
8mm	ø178	ø178	ø55	8.4	Max.	ø13.0	Max.	2.0	N/A	N/A	N/A
		±0.5	±1	+1.5/-0	14.4	±0.5	10.1	±0.5			

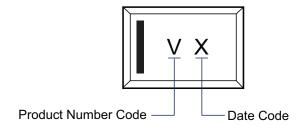
Leader / Trailer & Orientation







Part Marking



LEGAL DISCLAIMER

Alpha and Omega Semiconductor makes no representations or warranties with respect to the accuracy or completeness of the information provided herein and takes no liabilities for the consequences of use of such information or any product described herein. Alpha and Omega Semiconductor reserves the right to make changes to such information at any time without further notice. This document does not constitute the grant of any intellectual property rights or representation of non-infringement of any third party's intellectual property rights.

LIFE SUPPORT POLICY

ALPHA AND OMEGA SEMICONDUCTOR PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Rev. 5.0 November 2018 **www.aosmd.com** Page 7 of 7

单击下面可查看定价,库存,交付和生命周期等信息

>>AOS(万国半导体)